



**PATENT**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Ming-Sheng Yang Examiner: Pompey, Ron Everett

5 Chia-Hung Kao

Chin-Cheng Chien

Filing Date: 11/13/2002 Art Unit: 2812

App. No.: 10/065,717 Docket No.: NAUP0504USA

10 Title: METHOD OF PREVENTING LEAKAGE CURRENT OF A  
METAL-OXIDE SEMICONDUCTOR TRANSISTOR

To: Commissioner for Patents

P.O. BOX 1450

15 Alexandria, VA 22313-1450

**Subject:** Response to the Office Action dated 07/11/2003

Dear Sir or Madame:

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## INTRODUCTORY COMMENTS

In response to the Office action identified above, the above-identified application is to be amended as indicated